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CSD18540Q5B

SLPS488B-JUNE 2014-REVISED APRIL 2017

CSD18540Q5B 60-V, N-Channel NexFET™ Power MOSFETs

1 Features

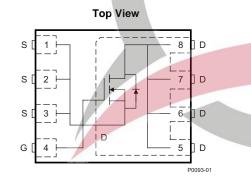
- Ultra-Low Q_a and Q_{ad}
- Low-Thermal Resistance
- Avalanche Rated
- Lead-Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

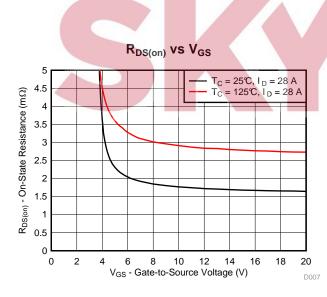
2 Applications

- DC-DC Conversion
- Secondary Side Synchronous Rectifier
- Isolated Converter Primary Side Switch
- Motor Control

3 Description

This 1.8-m Ω , 60-V NexFETTM power MOSFET is designed to minimize losses in power conversion applications with a SON 5-mm × 6-mm package.





Product Summary

T _A = 25°	C	TYPICAL VA	UNIT				
V _{DS}	Drain-to-Source Voltage 60						
Qg	Gate Charge Total (10 V) 41						
Q _{gd}	Gate Charge Gate-to-Drain	6.7	nC				
Р	Drain-to-Source On Resistance	$V_{GS} = 4.5 V$	mΩ				
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = 10 V	1.8	11175			
V _{GS(th)}	Threshold Voltage	1.9	V				

Device Information⁽¹⁾

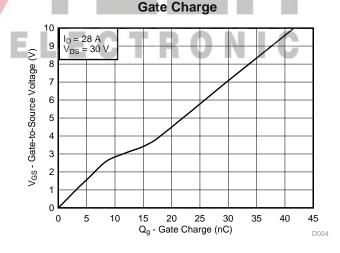
	DEVICE	QTY	MEDIA	PACKAGE	SHIP
_	CSD18540Q5B	2500	13-Inch Reel	SON	Таре
	CSD18540Q5BT	250	7-Inch Reel	5.00-mm × 6.00-mm Plastic Package	and Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T _A = 2	5°℃	١	VALUE		UNIT						
V _{DS}	Drain-to-Source Voltage	60			V						
V _{GS}	Gate-to-Source Voltage	±20			V						
	Continuous Drain Current (Package Limited) 100										
I _D	Continuous Drain Current (Silicon Limited), T _C = 25°C 205										
	Continuous Drain Current ⁽¹⁾ 29										
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$ 400										
D	Power Dissipation ⁽¹⁾		3.8		14/						
P _D	Power Dissipation, $T_c = 25^{\circ}C$	188			W						
T _J , T _{stg}	Operating Junction, Storage Temperature	-55 to 175									
E _{AS}	Avalanche Energy, Single Pulse I _D = 80 A, L = 0.1 mH, R _G = 25 Ω	Avalanche Energy, Single Pulse 220									

- (1) Typical $R_{\theta JA} = 40^{\circ}$ C/W on a 1-in², 2-oz Cu pad on a 0.06-in thick FR4 PCB.
- (2) Max $R_{\theta JC} = 0.8^{\circ}$ C/W, pulse duration $\leq 100 \ \mu$ s, duty cycle $\leq 1\%$.



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, **published by WWW.SKYTECH.IR** PATA.

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4 Revision History

Changes from Revision A (June 2016) to Revision B Page Changes from Original (June 2014) to Revision A Page Updated I_D values. Increased maximum temperature to 175°C. Changed Figure 6 to extend temperature to 175°C. 5 Changed Figure 8 to extend temperature to 175°C. Changed Figure 12 to extend temperature to 175°C. Added Receiving Notification of Documentation Updates and Community Resources to Device and Documentation

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5 Specifications

5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV _{DSS}	Drain-to-source voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	60			V
I _{DSS}	Drain-to-source leakage current	$V_{GS} = 0 V, V_{DS} = 48 V$			1	μA
I _{GSS}	Gate-to-source leakage current	$V_{DS} = 0 V, V_{GS} = 20 V$			100	nA
V _{GS(th)}	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I = 250 \ \mu A$	1.5	1.9	2.3	V
Р	Drain to course on registerios	V _{GS} = 4.5 V, I _D = 28 A		2.6	3.3	mΩ
R _{DS(on)}	Drain-to-source on resistance	V _{GS} = 10 V, I _D = 28 A		1.8	2.2	1117
9 _{fs}	Transconductance	$V_{DS} = 6 V, I_D = 28 A$		116		S
DYNAMI	C CHARACTERISTICS					
C _{iss}	Input capacitance			3250	4230	pF
C _{oss}	Output capacitance	V _{GS} = 0 V, V _{DS} = 30 V, <i>f</i> = 1 MHz		622	808	pF
C _{rss}	Reverse transfer capacitance			15	20	pF
R _G	Series gate resistance			0.8	1.6	Ω
Qg	Gate charge total (4.5 V)			20	26	nC
Qg	Gate charge total (10 V)			41	53	nC
Q _{gd}	Gate charge gate-to-drain	$V_{DS} = 30 \text{ V}, \text{ I}_{DD} = 28 \text{ A}$		6.7		nC
Q _{gs}	Gate charge gate-to-source			8.8		nC
Q _{g(th)}	Gate charge at V _{th}			6.3		nC
Q _{oss}	Output charge	V _{DS} = 30 V, V _{GS} = 0 V		83		nC
t _{d(on)}	Turnon delay time			6		ns
t _r	Rise time	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 10 \text{ V},$		9		ns
t _{d(off)}	Turnoff delay time	$I_{DS} = 28 \text{ A}, \text{ R}_{G} = 0 \Omega$		20		ns
t _f	Fall time			3		ns
DIODE C	CHARACTERISTICS					
V_{SD}	Diode forward voltage	I _{SD} = 28 A, V _{GS} = 0 V		0.8	1	V
Q _{rr}	Reverse recovery charge	V _{DS} = 30 V, I _F = 28 A,		145		nC
t _{rr}	Reverse recovery time	di/dt = 300 A/µs		82		ns

5.2 Thermal Information

T _A = 25°	C (unless otherwise stated)				
	THERMAL METRIC		MIN	TYP MAX	
$R_{\theta JC}$	Junction-to-case thermal resistance ⁽¹⁾			0.8	³ °C/W
R_{\thetaJA}	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾	ELEATE	0	50	

R_{θJC} is determined with the device mounted on a 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu pad on a 1.5-in x 1.5-in (3.81-cm × 3.81-cm), 0.06-in (1.52-mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.

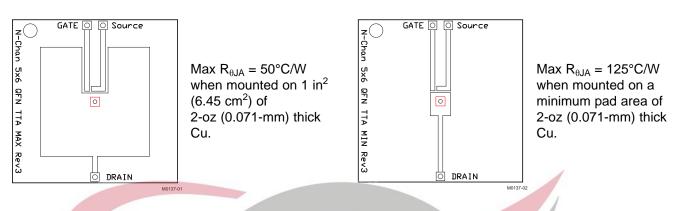
Product Folder Links: CSD18540Q5B

(2) Device mounted on FR4 material with 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu.

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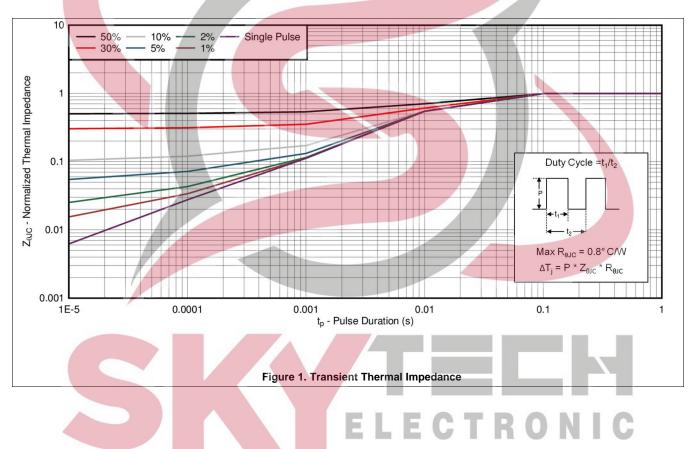


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5.3 Typical MOSFET Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise stated)



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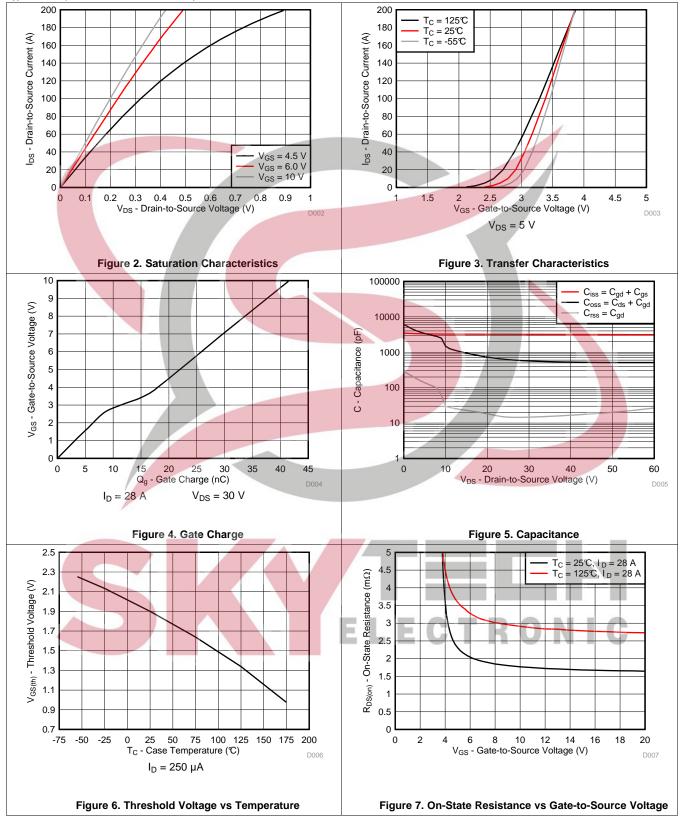
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Typical MOSFET Characteristics (continued)

 $T_A = 25^{\circ}C$ (unless otherwise stated)

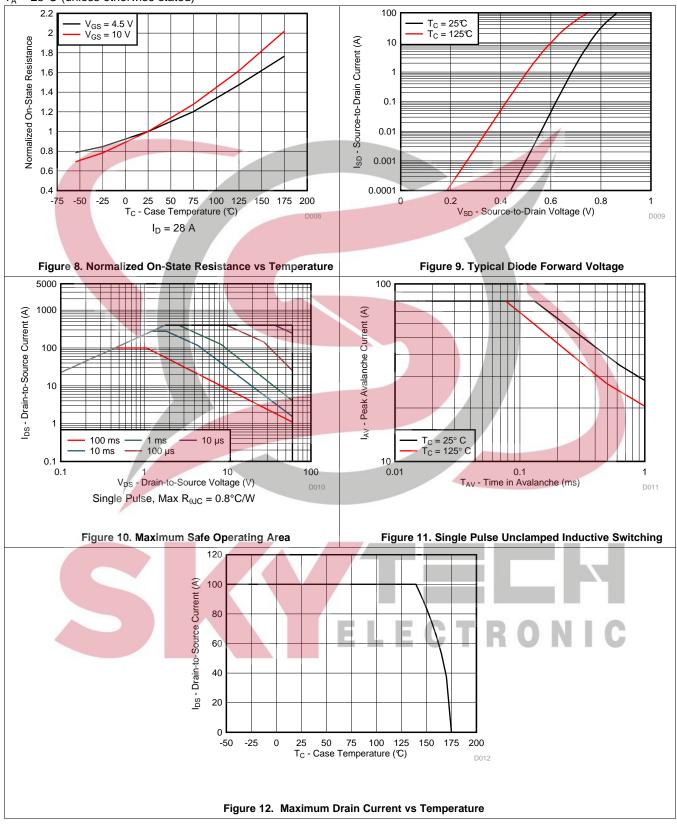


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Typical MOSFET Characteristics (continued)

 $T_A = 25^{\circ}C$ (unless otherwise stated)



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6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

NexFET, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

6.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.



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INSTRUMENTS

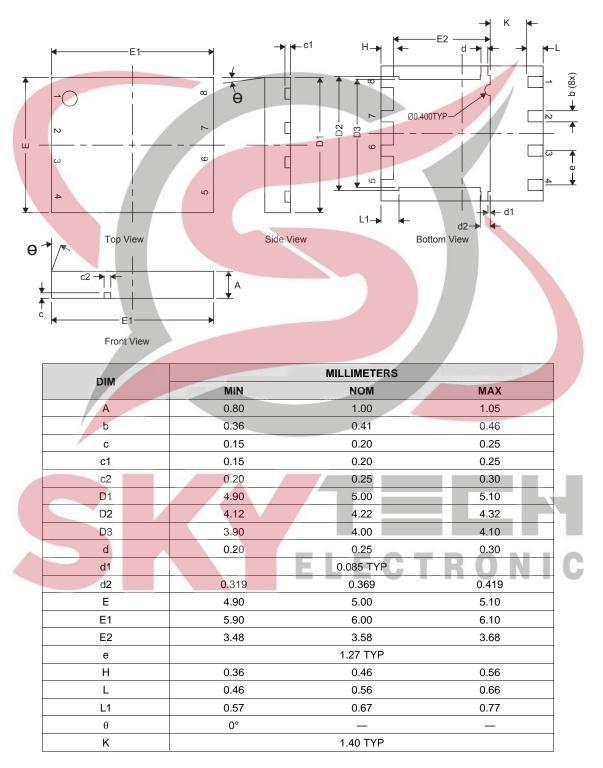
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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q5B Package Dimensions



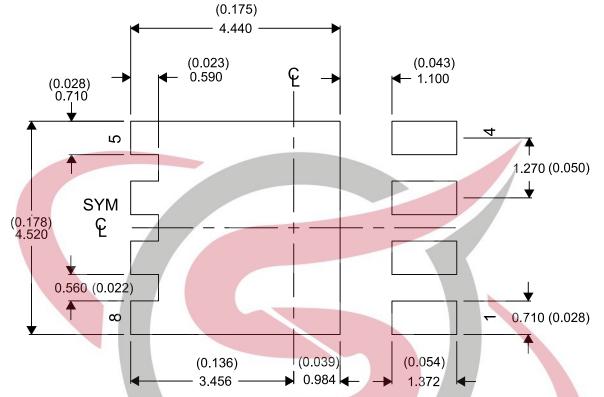
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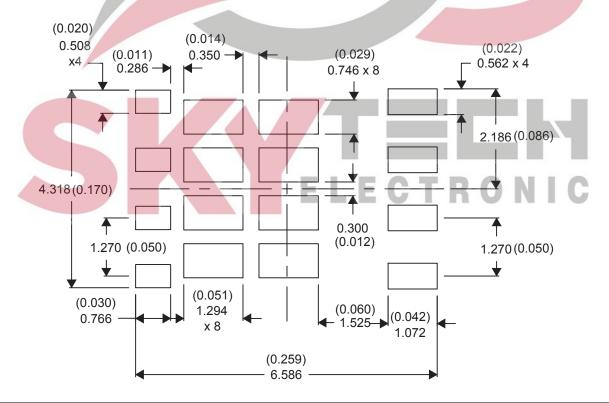


7.2 Recommended PCB Pattern



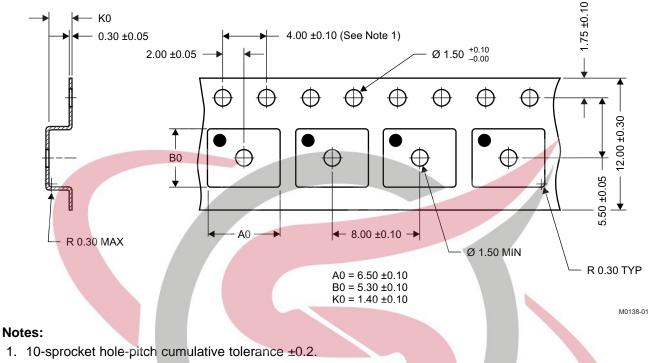
For recommended circuit layout for PCB designs, see *Reducing Ringing Through PCB Layout Techniques* (SLPA005).

7.3 Recommended Stencil Pattern



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7.4 Q5B Tape and Reel Information



- 2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm.
- 3. Material: black static-dissipative polystyrene.
- 4. All dimensions are in mm (unless otherwise specified).
- 5. A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket.

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10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Packag	е Туре	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD18540Q5B	ACTIVE	VSON	-CLIP	DNK	8	2500	RoHS-Exempt & Green	NIPDAU SN	Level-1-260C-UNLIM	-55 to 175	CSD18540	Samples
CSD18540Q5BT	ACTIVE	VSON	-CLIP	DNK	8	250	RoHS-Exempt & Green	NIPDAU SN	Level-1-260C-UNLIM	-55 to 175	CSD18540	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

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⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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Addendum-Page 2

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